# SPICE Device Model SiHF12N65E



**Vishay Siliconix** 

# **E Series Power MOSFET**

#### DESCRIPTION

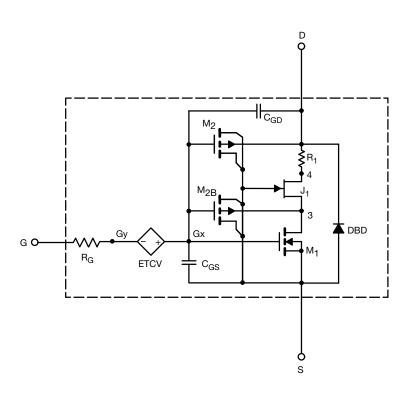
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +150 °C temperature ranges under the pulsed 0 V to 15 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}\xspace$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

#### SUBCIRCUIT MODEL SCHEMATIC



#### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static		-	•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	3.3	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS}$ = 10 V, $I_D$ = 6 A	0.35	0.33	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 6 \text{ A}$	5	3.5	S
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 24$ A, $V_{\rm GS} = 0$ V	0.90	1	V
Dynamic <sup>b</sup>		-	•		
Input Capacitance	Ciss	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, f = 1 MHz	1400	1224	pF
Output Capacitance	C <sub>oss</sub>		92	65	
Reverse Transfer Capacitance	C <sub>rss</sub>		7	4	
Total Gate Charge	Qg		35	35	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 520 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 6 \text{ A}$	9	9	nC
Gate-Drain Charge	Q <sub>gd</sub>		16	16	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

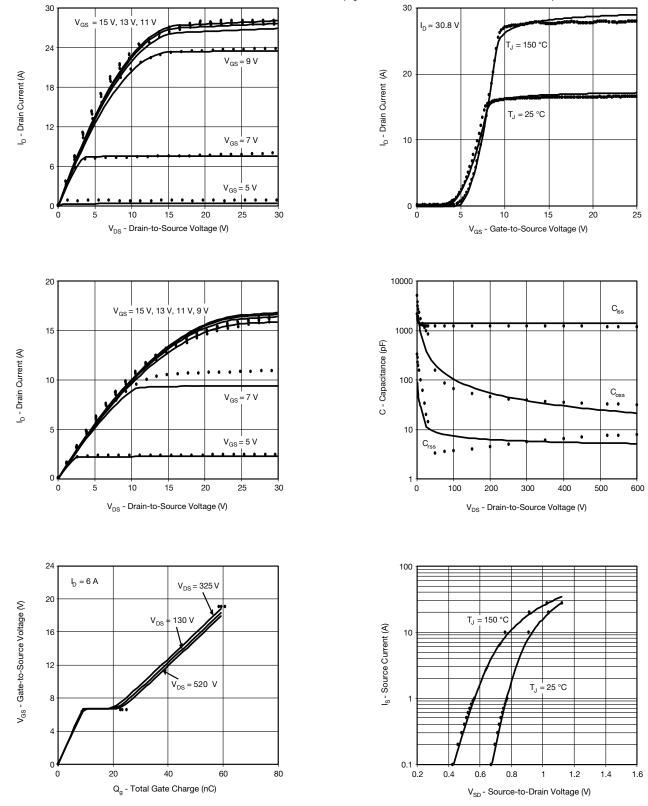
b. Guaranteed by design, not subject to production testing.



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### COMPARISON OF MODEL WITH MEASURED DATA (T\_J = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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